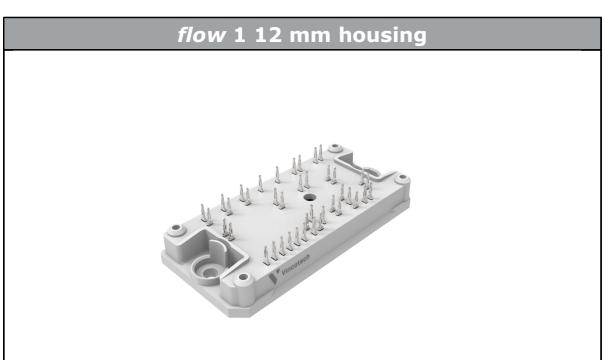
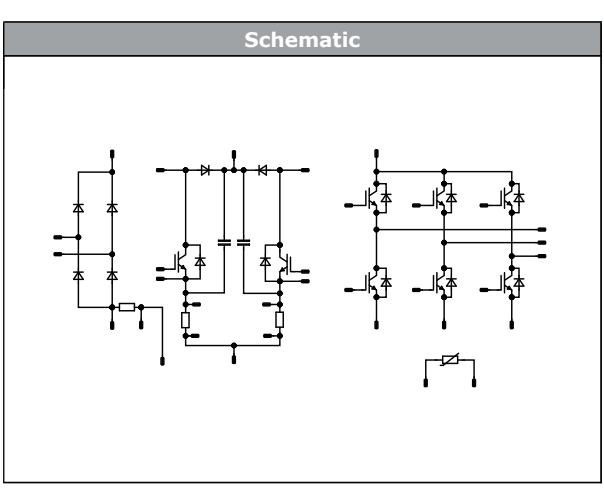




Vincotech

flowPIM 1 + PFC		600 V / 20 A
Features	 flow 1 12 mm housing	
<ul style="list-style-type: none">• One-phase rectifier• Interleaved PFC circuit• High speed IGBT in the inverter• Integrated shunts and capacitors• Built-in NTC		
Target applications	 Schematic	
<ul style="list-style-type: none">• Embedded Drives• Industrial Drives		
Types	<ul style="list-style-type: none">• 10-PG06PPA020SJ-LJ01B08T	



Vincotech

Maximum Ratings

$T_j = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Conditions	Value	Unit
Inverter Switch				
Collector-emitter voltage	V_{CES}		600	V
Collector current	I_C	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	23	A
Repetitive peak collector current	I_{CRM}	t_p limited by T_{jmax}	60	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	57	W
Gate-emitter voltage	V_{GES}		± 20	V
Short circuit ratings	t_{SC}	$V_{GE} = 15\text{ V}$, $V_{CC} = 400\text{ V}$ $T_j = 150^\circ\text{C}$	5	μs
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$
Inverter Diode				
Peak repetitive reverse voltage	V_{RRM}		600	V
Continuous (direct) forward current	I_F	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	21	A
Repetitive peak forward current	I_{FRM}	t_p limited by T_{jmax}	30	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	48	W
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$
PFC Switch				
Collector-emitter voltage	V_{CES}		650	V
Collector current	I_C	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	27	A
Repetitive peak collector current	I_{CRM}	t_p limited by T_{jmax}	60	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	56	W
Gate-emitter voltage	V_{GES}		± 20	V
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$



Vincotech

Maximum Ratings

$T_j = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Conditions	Value	Unit
PFC Diode				
Peak repetitive reverse voltage	V_{RRM}		650	V
Continuous (direct) forward current	I_F	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	25	A
Repetitive peak forward current	I_{FRM}	t_p limited by T_{jmax}	40	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	48	W
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$

PFC Sw. Protection Diode

Peak repetitive reverse voltage	V_{RRM}		650	V
Continuous (direct) forward current	I_F	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	8	A
Repetitive peak forward current	I_{FRM}	t_p limited by T_{jmax}	12	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	38	W
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$

Rectifier Diode

Peak repetitive reverse voltage	V_{RRM}		1600	V
Forward average current	I_{FAV}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	44	A
Surge (non-repetitive) forward current	I_{FSM}	Single Half Sine Wave, $t_p = 10 \text{ ms}$	270	A
Surge current capability	I_t	$T_j = 150^\circ\text{C}$	365	A^2s
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	64	W
Maximum junction temperature	T_{jmax}		150	$^\circ\text{C}$

PFC Shunt

DC current	I	terminal temperature Tk = 90 $^\circ\text{C}$	20	A
Power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	2	W
Operation Temperature	T_{op}		-65 ... 170	$^\circ\text{C}$



Vincotech

Maximum Ratings

$T_j = 25 \text{ }^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Conditions	Value	Unit
Shunt				
DC current	I	terminal temperature $T_k = 90 \text{ }^\circ\text{C}$	20	A
Power dissipation	P_{tot}	$T_j = T_{j\text{max}}$	2	W
Operation Temperature	T_{op}		-65 ... 170	$^\circ\text{C}$

Capacitor (PFC)

Maximum DC voltage	V_{MAX}		630	V
Operation Temperature	T_{op}		-55 ... 150	$^\circ\text{C}$

Module Properties

Thermal Properties

Storage temperature	T_{stg}		-40...+125	$^\circ\text{C}$
Operation temperature under switching condition	T_{jop}		-40...+($T_{j\text{max}} - 25$)	$^\circ\text{C}$

Isolation Properties

Isolation voltage	V_{isol}	DC Test Voltage* $t_p = 2 \text{ s}$	6000	V
Isolation voltage	V_{isol}	AC Voltage $t_p = 1 \text{ min}$	2500	V
Creepage distance			min. 12,7	mm
Clearance			7,82	mm
Comparative Tracking Index	CTI		≥ 600	

*100 % tested in production



Vincotech

Characteristic Values

Parameter	Symbol	Conditions					Values			Unit
		V_{GE} [V] V_{GS} [V]	V_{CE} [V] V_{DS} [V] V_F [V]	I_C [A] I_D [A] I_F [A]	T_j [°C]	Min	Typ	Max		

Inverter Switch

Static

Gate-emitter threshold voltage	$V_{GE(th)}$	$V_{CE} = V_{GE}$			0,00028	25	5	5,8	6,5	V
Collector-emitter saturation voltage	$V_{CE(sat)}$		15		20	25 125 150		1,83 2,06 2,12	1,8 ⁽¹⁾	V
Collector-emitter cut-off current	I_{CES}		0	600		25			0,6	µA
Gate-emitter leakage current	I_{GES}		20	0		25			100	nA
Internal gate resistance	r_g							None		Ω
Input capacitance	C_{res}	$f = 1 \text{ MHz}$	0	25	25	25	700	24	pF	pF
Reverse transfer capacitance	C_{res}									

Thermal

Thermal resistance junction to sink ⁽²⁾	$R_{th(j-s)}$	$\lambda_{\text{paste}} = 3,4 \text{ W/mK}$ (PSX)						1,67		K/W
--	---------------	--	--	--	--	--	--	------	--	-----

Dynamic

Turn-on delay time	$t_{d(on)}$	$R_{gon} = 16 \Omega$ $R_{goff} = 16 \Omega$	± 15	350	20	25		60,32		
Rise time	t_r					125		59,2		ns
						150		59,36		
Turn-off delay time	$t_{d(off)}$					25		30,08		
						125		31,2		
Fall time	t_f					150		31,2		ns
Turn-on energy (per pulse)	E_{on}	$Q_{rFWD}=0,559 \mu\text{C}$ $Q_{rFWD}=1,21 \mu\text{C}$ $Q_{rFWD}=1,48 \mu\text{C}$				25		86,88		
						125		107,36		
						150		111,84		
Turn-off energy (per pulse)	E_{off}					25		22,21		
						125		38,32		
						150		43,74		ns
						25		0,414		
						125		0,55		
						150		0,588		mWs
						25		0,229		
						125		0,369		
						150		0,403		mWs



Vincotech

Characteristic Values

Parameter	Symbol	Conditions						Values			Unit
		V_{GE} [V]	V_{GS} [V]	V_{CE} [V]	V_{DS} [V]	I_C [A]	I_D [A]	T_j [°C]	Min	Typ	Max

Inverter Diode

Static

Forward voltage	V_F				15	25 125 150	1,25	1,76 1,66 1,61	1,95 ⁽¹⁾	V
Reverse leakage current	I_R	$V_F = 600$ V			25			27	μ A	

Thermal

Thermal resistance junction to sink ⁽²⁾	$R_{th(j-s)}$	$\lambda_{paste} = 3,4$ W/mK (PSX)						1,99		K/W
--	---------------	---------------------------------------	--	--	--	--	--	------	--	-----

Dynamic

Peak recovery current	I_{RRM}	$di/dt=537$ A/ μ s $di/dt=702$ A/ μ s $di/dt=573$ A/ μ s	± 15	350	20	25 125 150		6,64 9,71 10,67		A
Reverse recovery time	t_{rr}					25 125 150		198,64 271,14 309,91		ns
Recovered charge	Q_r					25 125 150		0,559 1,21 1,48		μ C
Reverse recovered energy	E_{rec}					25 125 150		0,138 0,303 0,378		mWs
Peak rate of fall of recovery current	$(di_{rr}/dt)_{max}$					25 125 150		30,78 67,04 68,48		A/μ s



10-PG06PPA020SJ-LJ01B08T

datasheet

Vincotech

Characteristic Values

Parameter	Symbol	Conditions					Values			Unit
		V_{GE} [V]	V_{GS} [V]	V_{CE} [V]	V_{DS} [V]	I_C [A]	T_j [°C]	Min	Typ	

PFC Switch

Static

Gate-emitter threshold voltage	$V_{GE(th)}$	$V_{CE} = V_{GE}$			0,0002	25	3,3	4	4,7	V
Collector-emitter saturation voltage	$V_{CE(sat)}$		15		20	25 125 150		1,54 1,69 1,74	2,22 ⁽¹⁾	V
Collector-emitter cut-off current	I_{CES}		0	650		25			40	µA
Gate-emitter leakage current	I_{GES}		20	0		25			120	nA
Internal gate resistance	r_g							None		Ω
Input capacitance	C_{res}	$f = 1 \text{ MHz}$	0	25	25	25		1200		pF
Output capacitance	C_{oes}							30		pF
Reverse transfer capacitance	C_{res}							5		pF
Gate charge	Q_g	$V_{CC} = 520 \text{ V}$	15		20	25		48		nC

Thermal

Thermal resistance junction to sink ⁽²⁾	$R_{th(j-s)}$	$\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX)						1,7		K/W
--	---------------	---	--	--	--	--	--	-----	--	-----

Dynamic

Turn-on delay time	$t_{d(on)}$	$R_{gon} = 16 \Omega$ $R_{goff} = 16 \Omega$	0/15	400	20	25		17		
Rise time	t_r					125		19		ns
Turn-off delay time	$t_{d(off)}$					150		13		
Fall time	t_f					25		9		
Turn-on energy (per pulse)	E_{on}					125		11		
Turn-off energy (per pulse)	E_{off}					150		9		
						25		99		
						125		115		
						150		120		
						25		8,08		
						125		13,64		
						150		10,32		
						25		0,315		
						125		0,36		
						150		0,47		mWs
						25		0,064		
						125		0,146		
						150		0,11		mWs



Vincotech

Characteristic Values

Parameter	Symbol	Conditions						Values			Unit
		V_{GE} [V]	V_{GS} [V]	V_{CE} [V]	V_{DS} [V]	I_C [A]	I_D [A]	T_j [°C]	Min	Typ	Max

PFC Diode

Static

Forward voltage	V_F				20	25 125 150		1,82 1,8 1,76	2,22 ⁽¹⁾	V
Reverse leakage current	I_R	$V_F = 650$ V			25			1,28	μ A	

Thermal

Thermal resistance junction to sink ⁽²⁾	$R_{th(j-s)}$	$\lambda_{paste} = 3,4$ W/mK (PSX)						1,96		K/W
--	---------------	---------------------------------------	--	--	--	--	--	------	--	-----

Dynamic

Peak recovery current	I_{RRM}	$di/dt=2664$ A/ μ s $di/dt=2094$ A/ μ s $di/dt=2443$ A/ μ s	0/15	400	20	25 125 150		15,35 19,92 24		A
Reverse recovery time	t_{rr}					25 125 150		32,73 40,14 41,74		ns
Recovered charge	Q_r					25 125 150		0,307 0,491 0,612		μ C
Reverse recovered energy	E_{rec}					25 125 150		0,06 0,109 0,097		mWs
Peak rate of fall of recovery current	$(di_{rr}/dt)_{max}$					25 125 150		848,64 985,81 965,97		A/ μ s



Vincotech

Characteristic Values

Parameter	Symbol	Conditions						Values			Unit
		V_{GE} [V]	V_{GS} [V]	V_{CE} [V]	V_{DS} [V]	I_C [A]	I_D [A]	T_j [°C]	Min	Typ	Max

PFC Sw. Protection Diode

Static

Forward voltage	V_F				6	25 125 150	1,23	1,72 1,58 1,53	1,87 ⁽¹⁾	V
Reverse leakage current	I_R	$V_F = 650$ V			25			0,1	μ A	

Thermal

Thermal resistance junction to sink ⁽²⁾	$R_{th(j-s)}$	$\lambda_{paste} = 3,4$ W/mK (PSX)						2,53		K/W
--	---------------	---------------------------------------	--	--	--	--	--	------	--	-----

Rectifier Diode

Static

Forward voltage	V_F				31	25 125		1,14 1,1		V
Reverse leakage current	I_R	$V_F = 1600$ V			25 150			20 1500	μ A	

Thermal

Thermal resistance junction to sink ⁽²⁾	$R_{th(j-s)}$	$\lambda_{paste} = 3,4$ W/mK (PSX)						1,1		K/W
--	---------------	---------------------------------------	--	--	--	--	--	-----	--	-----

PFC Shunt

Static

Resistance	R							5		$m\Omega$
Tolerance							1		1	%
Temperature coefficient	t_c							20	ppm/K	



Vincotech

Characteristic Values

Parameter	Symbol	Conditions						Values			Unit
		V_{GE} [V]	V_{GS} [V]	V_{CE} [V]	V_{DS} [V]	I_C [A]	I_D [A]	T_j [°C]	Min	Typ	Max

Shunt

Static

Resistance	R							5			mΩ
Tolerance								1		1	%
Temperature coefficient	t_c								20	ppm/K	

Capacitor (PFC)

Static

Capacitance	C	DC bias voltage = 0 V				25		33			nF
Tolerance							-5		5		%

Thermistor

Static

Rated resistance	R				25		22				kΩ
Deviation of R_{100}	$\Delta_{R/R}$	$R_{100} = 1484 \Omega$			100	-5		5			%
Power dissipation	P						5				mW
Power dissipation constant	d				25		1,5				mW/K
B-value	$B_{(25/50)}$	Tol. ±1 %					3962				K
B-value	$B_{(25/100)}$	Tol. ±1 %					4000				K
Vincotech Thermistor Reference									I		

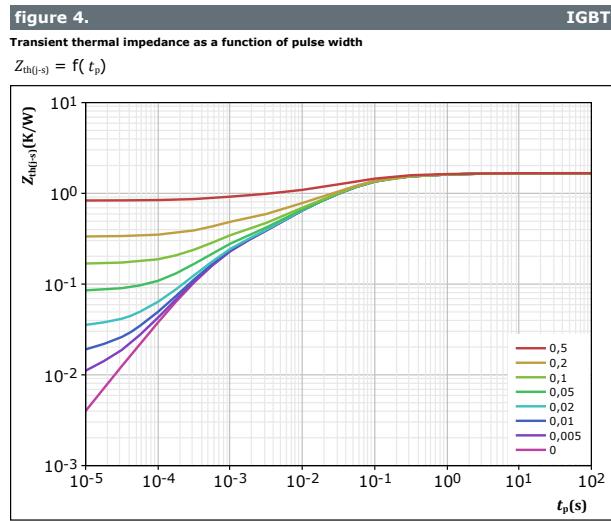
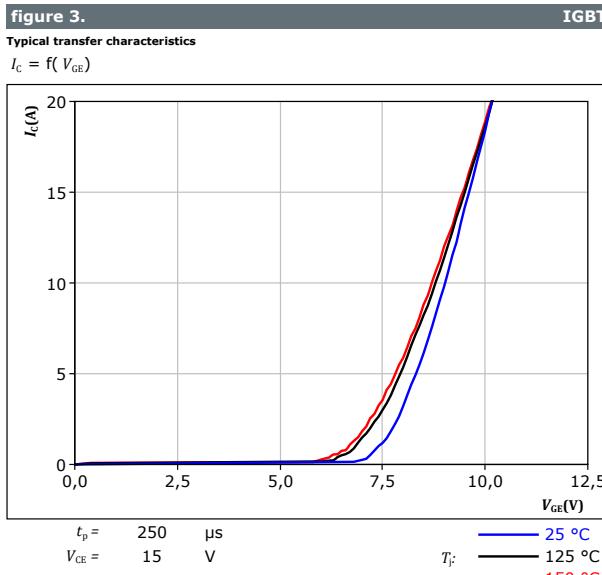
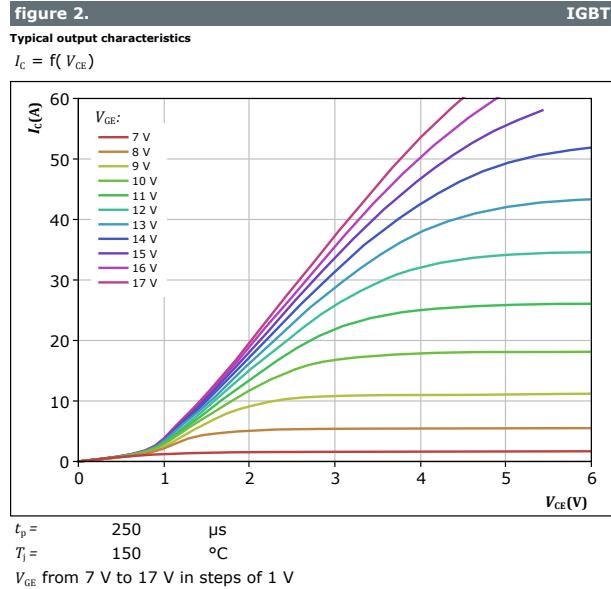
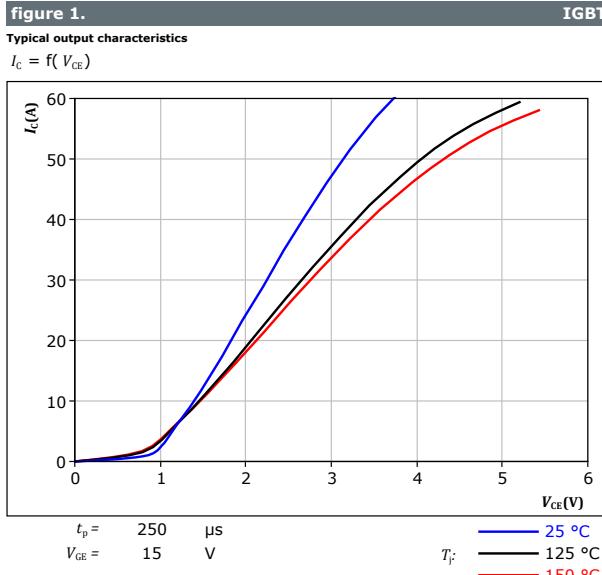
(1) Value at chip level

(2) Only valid with pre-applied Vincotech thermal interface material.



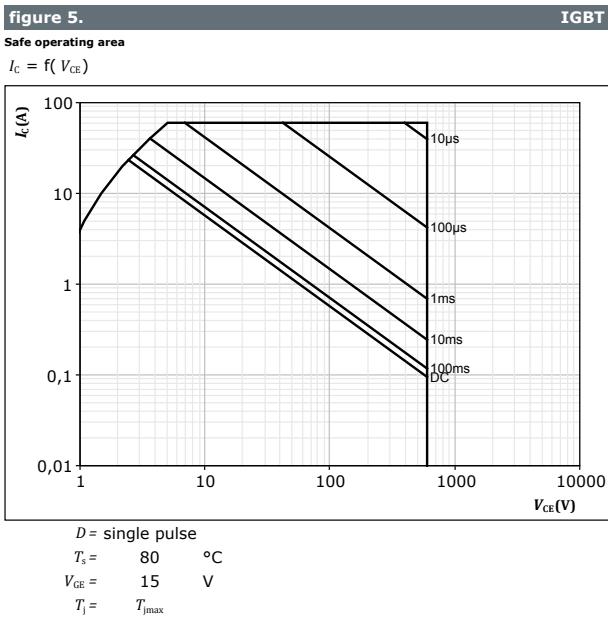
Vincotech

Inverter Switch Characteristics



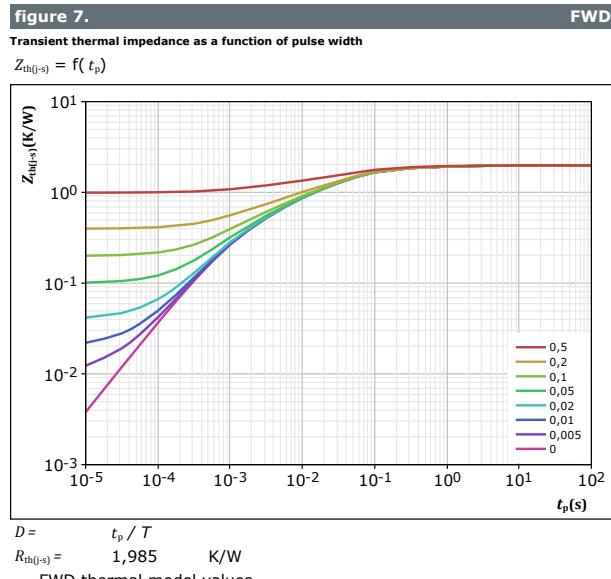
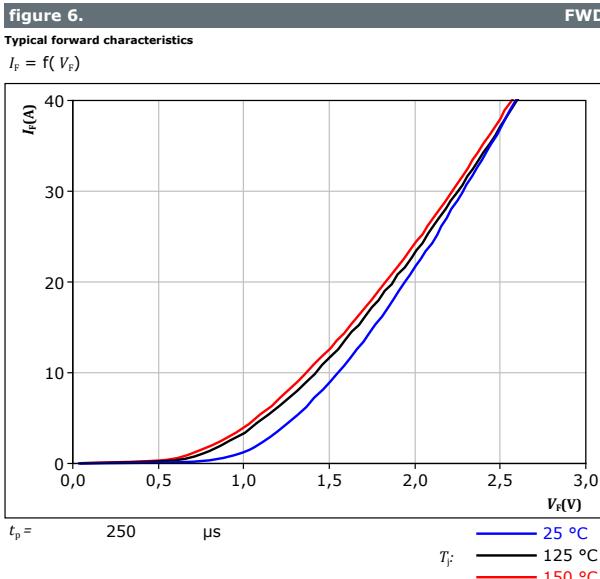


Inverter Switch Characteristics





Inverter Diode Characteristics





Vincotech

PFC Switch Characteristics

figure 8. IGBT

Typical output characteristics
 $I_C = f(V_{CE})$

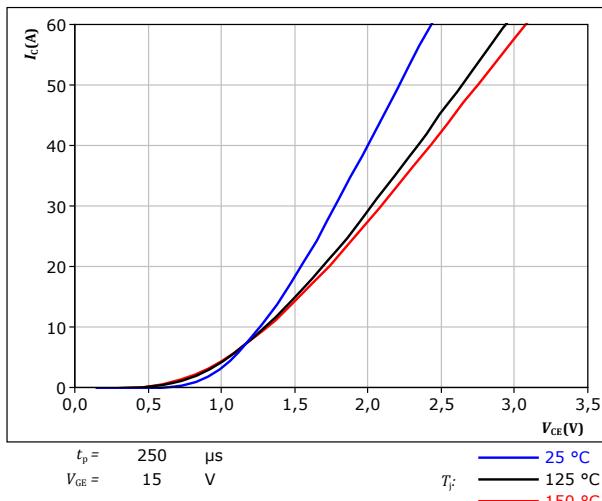


figure 9. IGBT

Typical output characteristics
 $I_C = f(V_{CE})$

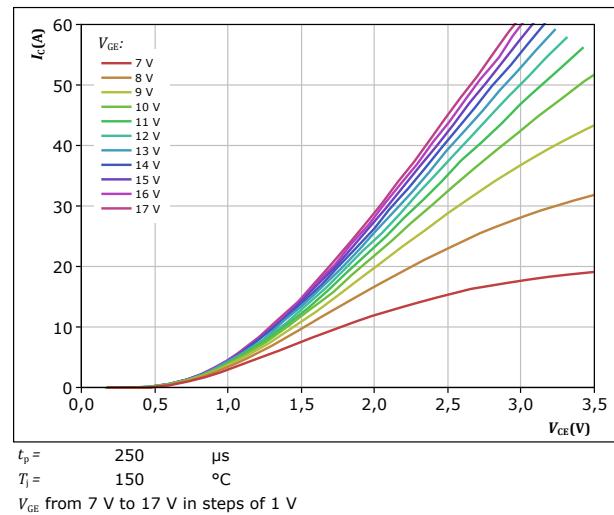


figure 10. IGBT

Typical transfer characteristics
 $I_C = f(V_{GE})$

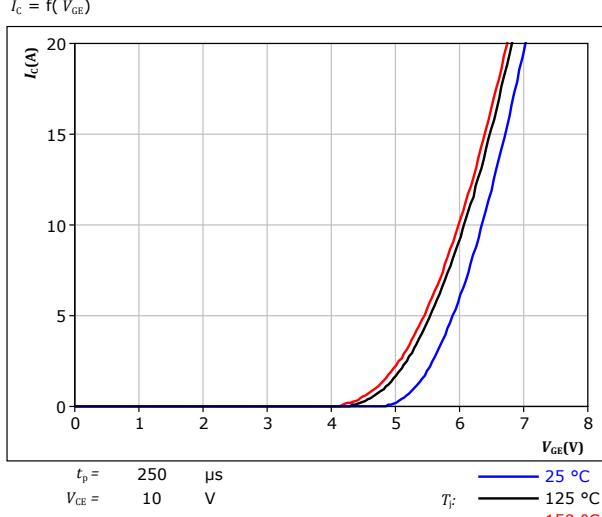
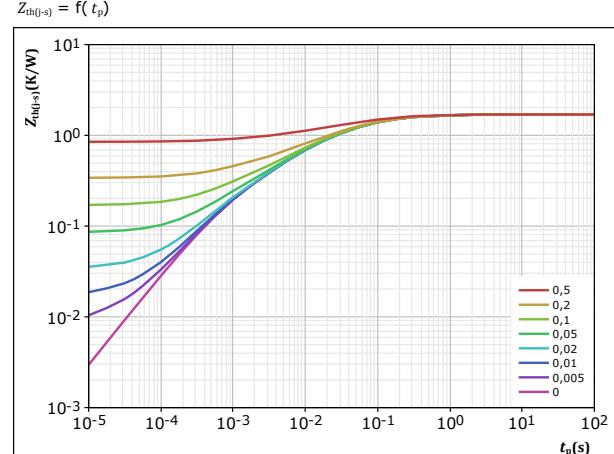


figure 11. IGBT

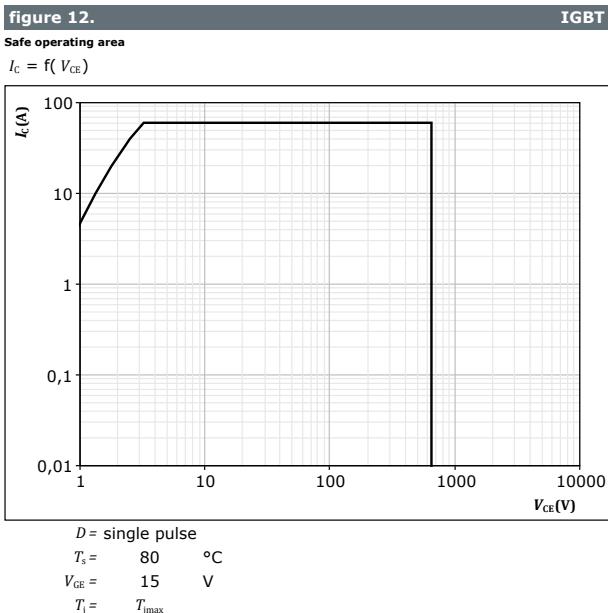
Transient thermal impedance as a function of pulse width
 $Z_{th(j-s)} = f(t_p)$



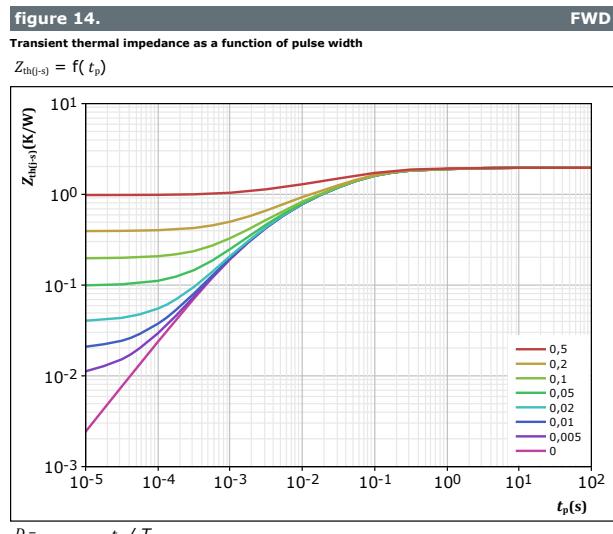
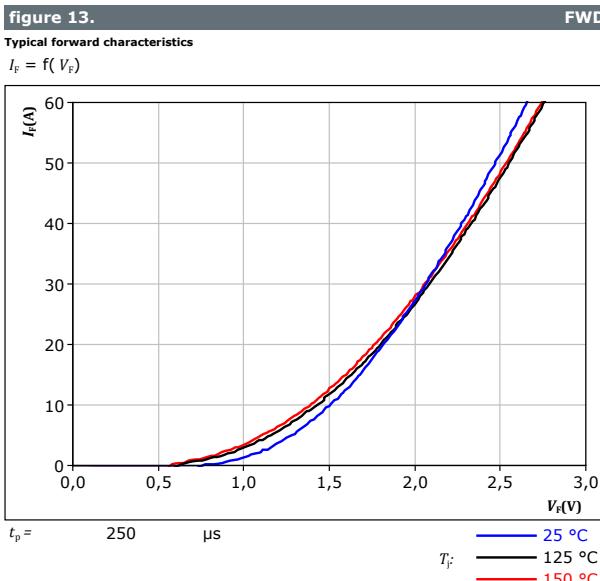
R (K/W)	τ (s)
1,45E-01	7,07E-01
5,50E-01	8,69E-02
5,51E-01	2,05E-02
3,26E-01	4,56E-03
1,26E-01	6,55E-04



PFC Switch Characteristics



PFC Diode Characteristics





Vincotech

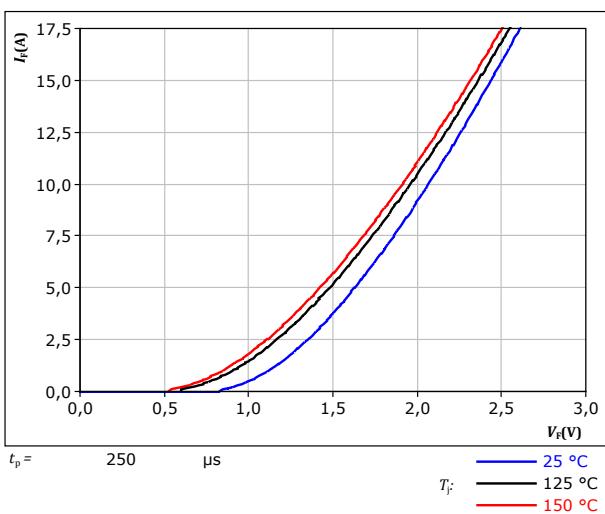
PFC Sw. Protection Diode Characteristics

figure 15.

Typical forward characteristics

$$I_F = f(V_F)$$

FWD



$$t_p = 250 \mu\text{s}$$

$$T_F:$$

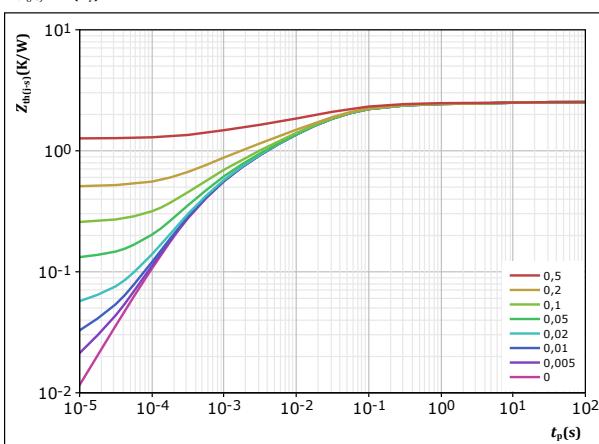
- 25 °C
- 125 °C
- 150 °C

figure 16.

Transient thermal impedance as a function of pulse width

$$Z_{th(t-s)} = f(t_p)$$

FWD



$$D = \frac{t_p}{T} = 2,527 \text{ K/W}$$

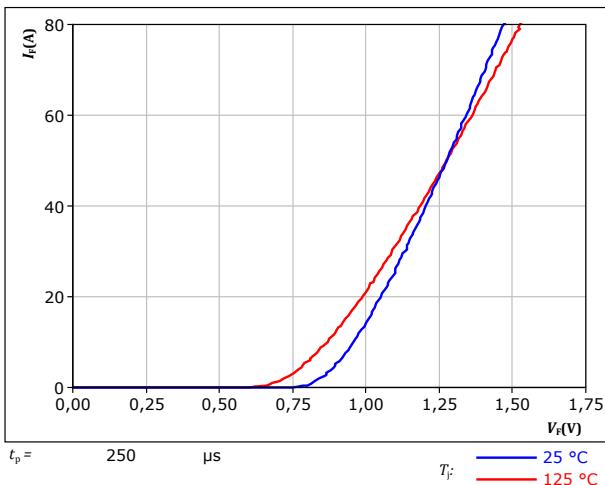
FWD thermal model values

R (K/W)	τ (s)
9,24E-02	9,29E+00
1,75E-01	3,21E-01
7,31E-01	4,97E-02
7,14E-01	1,16E-02
4,89E-01	2,11E-03
3,27E-01	3,78E-04



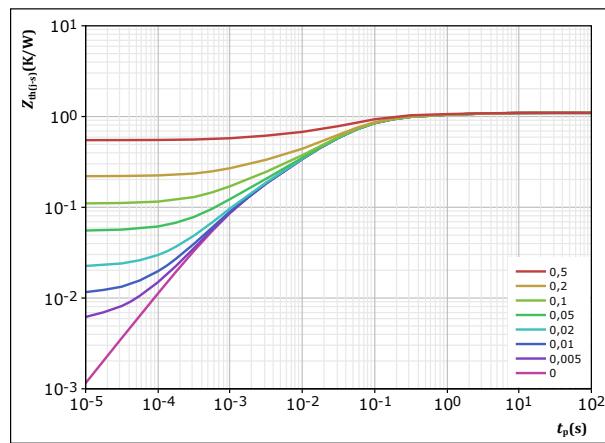
Rectifier Diode Characteristics

figure 17.
Typical forward characteristics
 $I_F = f(V_F)$



Rectifier

figure 18.
Transient thermal impedance as a function of pulse width
 $Z_{th(j-s)} = f(t_p)$



Rectifier

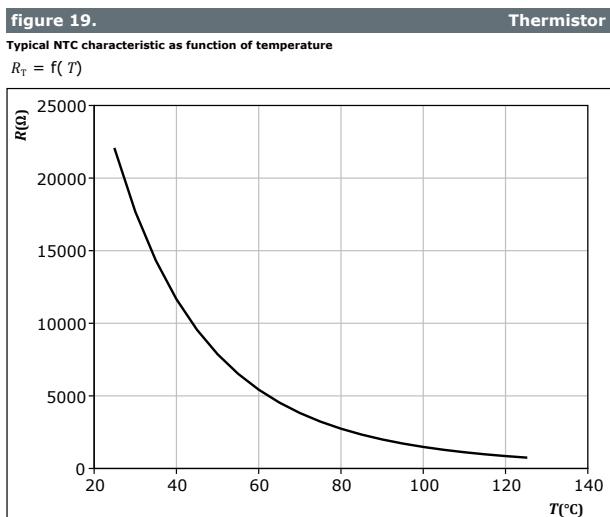
$$D = \frac{t_p / T}{1,098} \quad K/W$$

Rectifier thermal model values

R (K/W)	τ (s)
4,35E-02	3,78E+00
9,34E-02	6,17E-01
3,79E-01	8,75E-02
3,82E-01	2,72E-02
1,24E-01	5,56E-03
7,66E-02	1,02E-03



Thermistor Characteristics





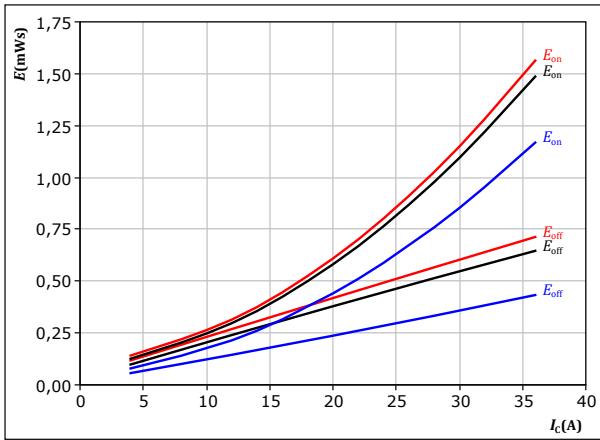
Vincotech

Inverter Switching Characteristics

figure 20.

Typical switching energy losses as a function of collector current

$$E = f(I_c)$$



With an inductive load at

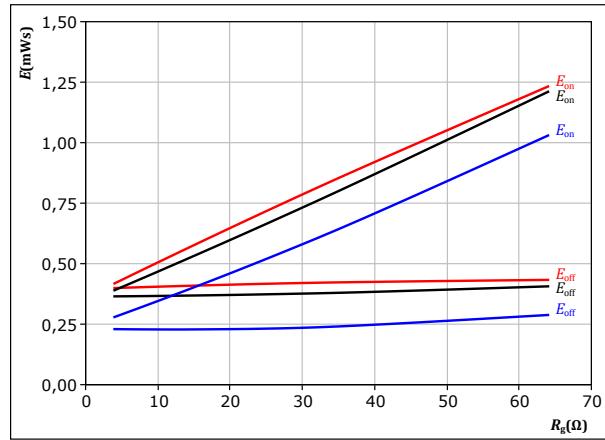
V_{CE} =	350	V
V_{GE} =	± 15	V
R_{gon} =	16	Ω
R_{goff} =	16	Ω

IGBT

figure 21.

Typical switching energy losses as a function of gate resistor

$$E = f(R_g)$$



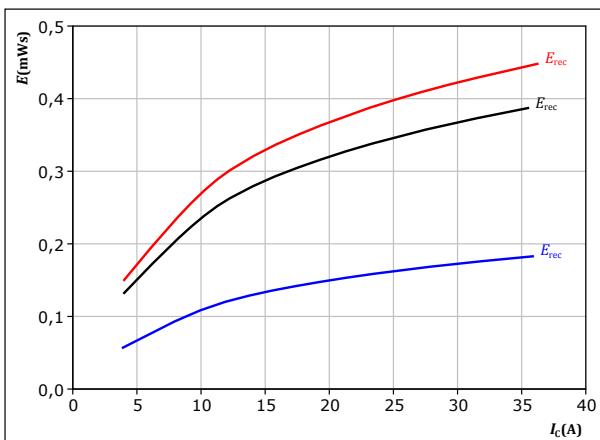
With an inductive load at

V_{CE} =	350	V
V_{GE} =	± 15	V
I_c =	20	A

figure 22.

Typical reverse recovered energy loss as a function of collector current

$$E_{rec} = f(I_c)$$



With an inductive load at

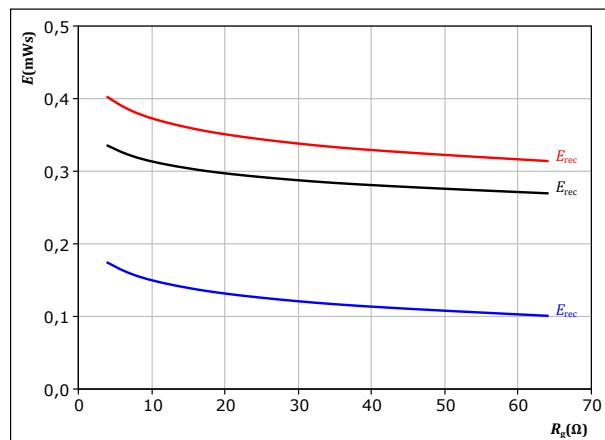
V_{CE} =	350	V
V_{GE} =	± 15	V
R_{gon} =	16	Ω

FWD

figure 23.

Typical reverse recovered energy loss as a function of gate resistor

$$E_{rec} = f(R_g)$$



With an inductive load at

V_{CE} =	350	V
V_{GE} =	± 15	V
I_c =	20	A



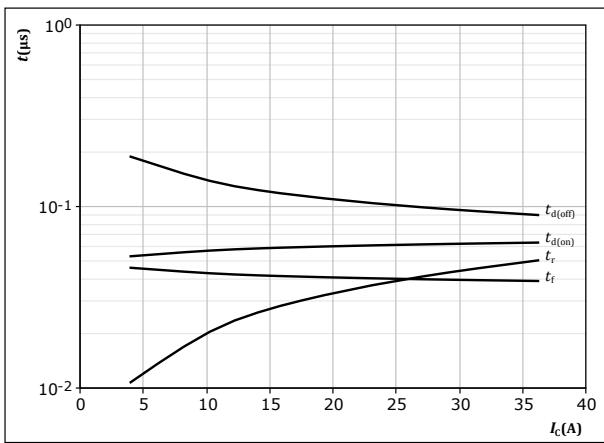
Vincotech

Inverter Switching Characteristics

figure 24.

IGBT

Typical switching times as a function of collector current
 $t = f(I_C)$



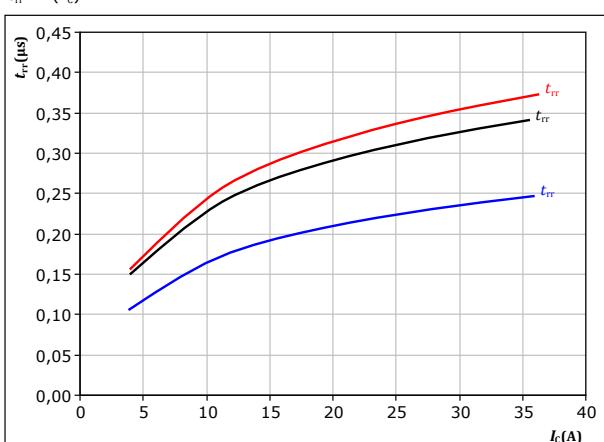
With an inductive load at

$T_j = 150^\circ\text{C}$
 $V_{CE} = 350 \text{ V}$
 $V_{GE} = \pm 15 \text{ V}$
 $R_{gon} = 16 \Omega$
 $R_{goff} = 16 \Omega$

figure 26.

FWD

Typical reverse recovery time as a function of collector current
 $t_{rr} = f(I_C)$



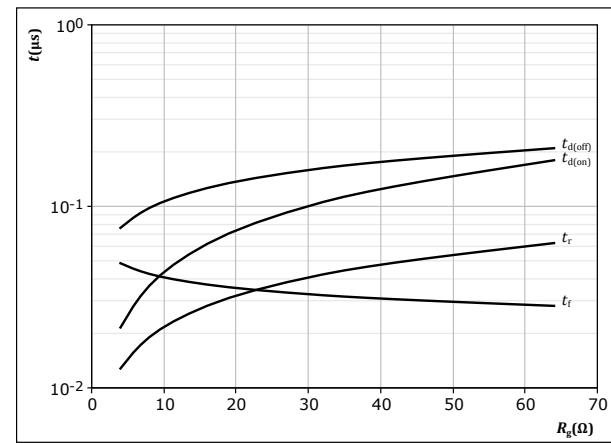
With an inductive load at

$V_{CE} = 350 \text{ V}$
 $V_{GE} = \pm 15 \text{ V}$
 $R_{gon} = 16 \Omega$

figure 25.

IGBT

Typical switching times as a function of gate resistor
 $t = f(R_g)$



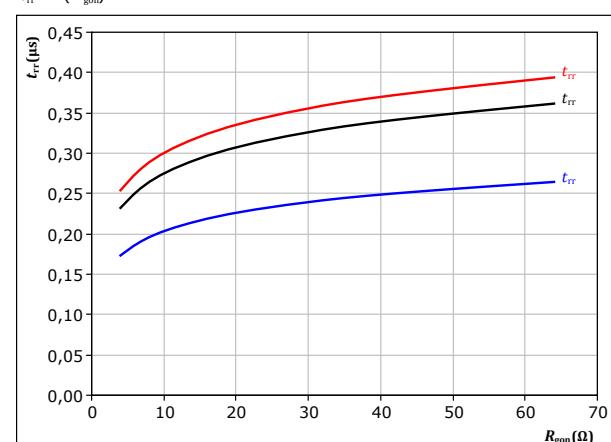
With an inductive load at

$T_j = 150^\circ\text{C}$
 $V_{CE} = 350 \text{ V}$
 $V_{GE} = \pm 15 \text{ V}$
 $I_C = 20 \text{ A}$

figure 27.

FWD

Typical reverse recovery time as a function of IGBT turn on gate resistor
 $t_{rr} = f(R_{gon})$



With an inductive load at

$V_{CE} = 350 \text{ V}$
 $V_{GE} = \pm 15 \text{ V}$
 $I_C = 20 \text{ A}$



Vincotech

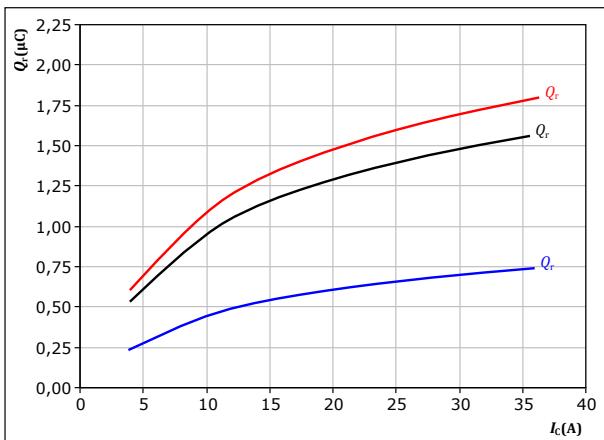
Inverter Switching Characteristics

figure 28.

FWD

Typical recovered charge as a function of collector current

$$Q_r = f(I_c)$$



With an inductive load at

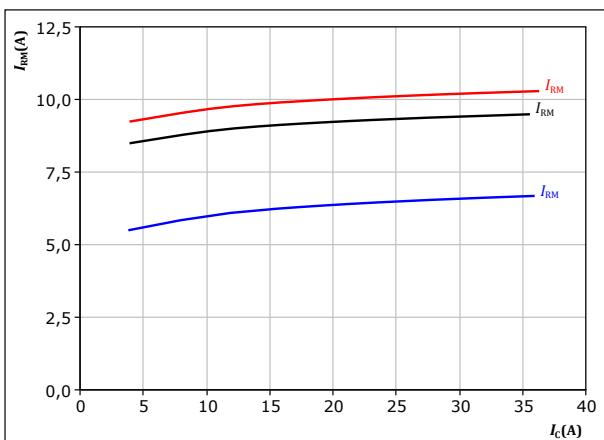
$$\begin{aligned} V_{CE} &= 350 \text{ V} & T_f &= 125 \text{ °C} \\ V_{GE} &= \pm 15 \text{ V} & & \\ R_{gon} &= 16 \Omega & & \end{aligned}$$

figure 30.

FWD

Typical peak reverse recovery current as a function of collector current

$$I_{RM} = f(I_c)$$



With an inductive load at

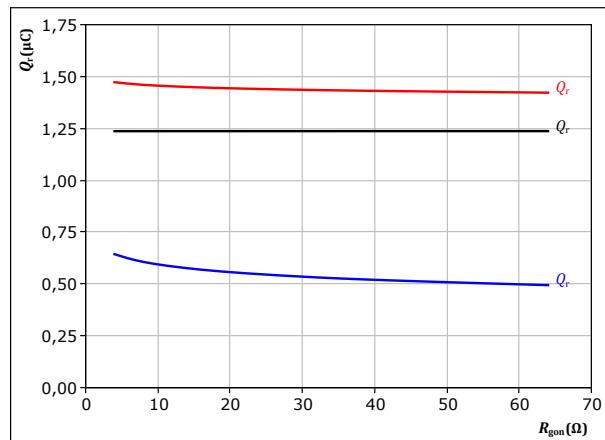
$$\begin{aligned} V_{CE} &= 350 \text{ V} & T_f &= 125 \text{ °C} \\ V_{GE} &= \pm 15 \text{ V} & & \\ R_{gon} &= 16 \Omega & & \end{aligned}$$

figure 29.

FWD

Typical recovered charge as a function of turn on gate resistor

$$Q_r = f(R_{gon})$$



With an inductive load at

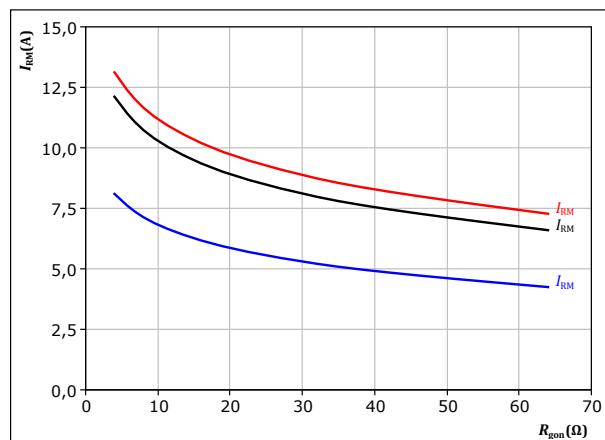
$$\begin{aligned} V_{CE} &= 350 \text{ V} & T_f &= 125 \text{ °C} \\ V_{GE} &= \pm 15 \text{ V} & & \\ I_c &= 20 \text{ A} & & \end{aligned}$$

figure 31.

FWD

Typical peak reverse recovery current as a function of turn on gate resistor

$$I_{RM} = f(R_{gon})$$



With an inductive load at

$$\begin{aligned} V_{CE} &= 350 \text{ V} & T_f &= 125 \text{ °C} \\ V_{GE} &= \pm 15 \text{ V} & & \\ I_c &= 20 \text{ A} & & \end{aligned}$$

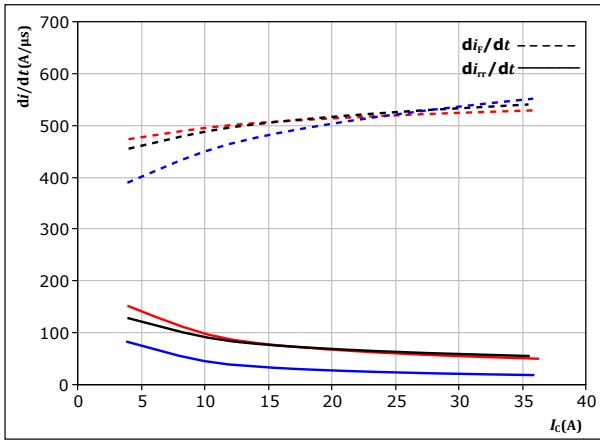


Vincotech

Inverter Switching Characteristics

figure 32. FWD

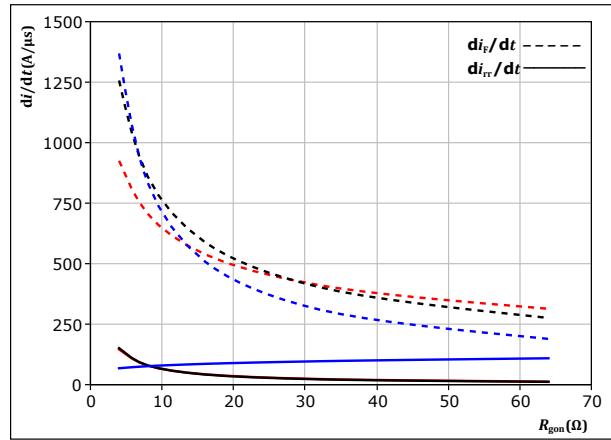
Typical rate of fall of forward and reverse recovery current as a function of collector current
 $di_f/dt, di_{rr}/dt = f(I_c)$



With an inductive load at
 $V_{CE} = 350$ V $T_j = 25^\circ\text{C}$
 $V_{GE} = \pm 15$ V $T_j = 125^\circ\text{C}$
 $R_{gon} = 16$ Ω $T_j = 150^\circ\text{C}$

figure 33. FWD

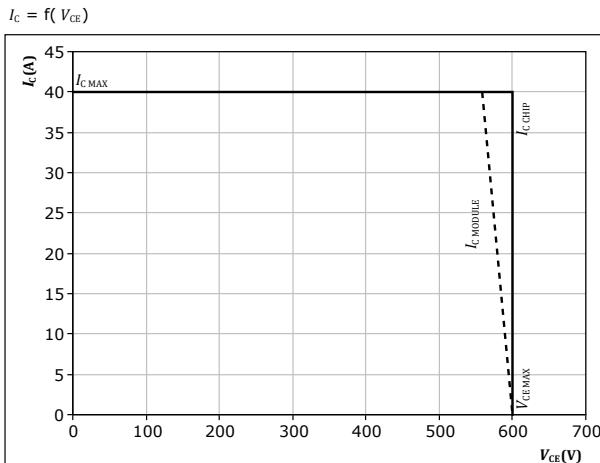
Typical rate of fall of forward and reverse recovery current as a function of turn on gate resistor
 $di_f/dt, di_{rr}/dt = f(R_{gon})$



With an inductive load at
 $V_{CE} = 350$ V $T_j = 25^\circ\text{C}$
 $V_{GE} = \pm 15$ V $T_j = 125^\circ\text{C}$
 $I_c = 20$ A $T_j = 150^\circ\text{C}$

figure 34. IGBT

Reverse bias safe operating area
 $I_c = f(V_{CE})$



At $T_j = 150^\circ\text{C}$
 $R_{gon} = 16$ Ω
 $R_{goff} = 16$ Ω



Vincotech

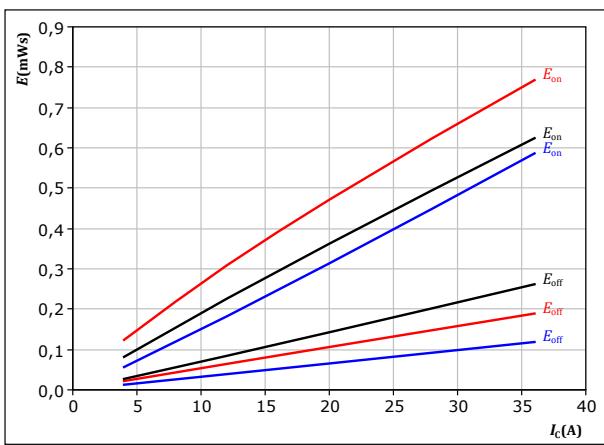
PFC Switching Characteristics

figure 35.

Typical switching energy losses as a function of collector current

IGBT

$$E = f(I_c)$$



With an inductive load at

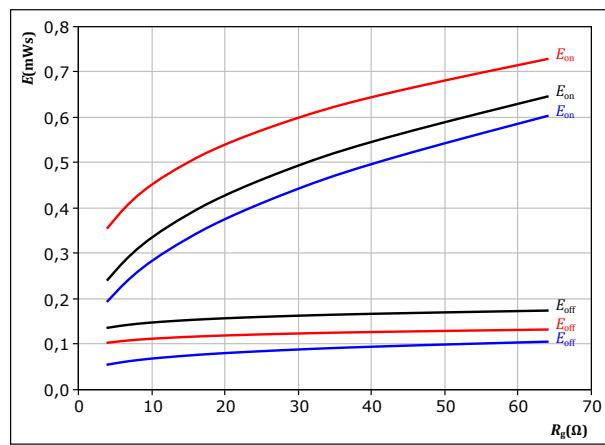
$$\begin{aligned} V_{CE} &= 400 \quad V \\ V_{GE} &= 0/15 \quad V \\ R_{gon} &= 16 \quad \Omega \\ R_{goff} &= 16 \quad \Omega \end{aligned} \quad T_f: \begin{array}{ll} \text{---} & 25 \text{ }^{\circ}\text{C} \\ \text{---} & 125 \text{ }^{\circ}\text{C} \\ \text{---} & 150 \text{ }^{\circ}\text{C} \end{array}$$

figure 36.

Typical switching energy losses as a function of gate resistor

IGBT

$$E = f(R_g)$$



With an inductive load at

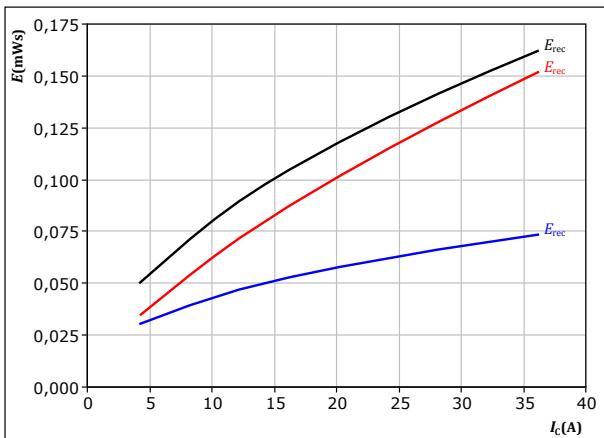
$$\begin{aligned} V_{CE} &= 400 \quad V \\ V_{GE} &= 0/15 \quad V \\ I_c &= 20 \quad A \end{aligned} \quad T_f: \begin{array}{ll} \text{---} & 25 \text{ }^{\circ}\text{C} \\ \text{---} & 125 \text{ }^{\circ}\text{C} \\ \text{---} & 150 \text{ }^{\circ}\text{C} \end{array}$$

figure 37.

Typical reverse recovered energy loss as a function of collector current

FWD

$$E_{rec} = f(I_c)$$



With an inductive load at

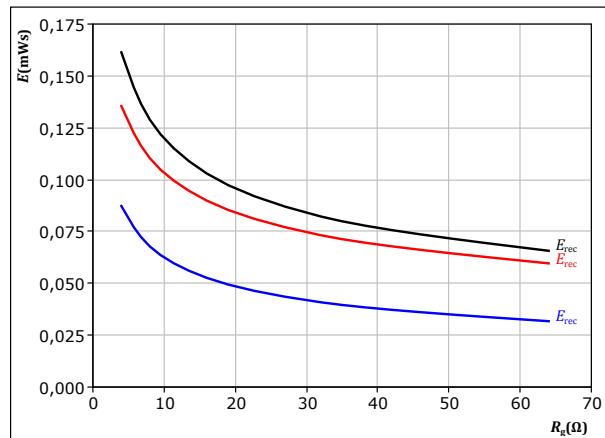
$$\begin{aligned} V_{CE} &= 400 \quad V \\ V_{GE} &= 0/15 \quad V \\ R_{gon} &= 16 \quad \Omega \end{aligned} \quad T_f: \begin{array}{ll} \text{---} & 25 \text{ }^{\circ}\text{C} \\ \text{---} & 125 \text{ }^{\circ}\text{C} \\ \text{---} & 150 \text{ }^{\circ}\text{C} \end{array}$$

figure 38.

Typical reverse recovered energy loss as a function of gate resistor

FWD

$$E_{rec} = f(R_g)$$



With an inductive load at

$$\begin{aligned} V_{CE} &= 400 \quad V \\ V_{GE} &= 0/15 \quad V \\ I_c &= 20 \quad A \end{aligned} \quad T_f: \begin{array}{ll} \text{---} & 25 \text{ }^{\circ}\text{C} \\ \text{---} & 125 \text{ }^{\circ}\text{C} \\ \text{---} & 150 \text{ }^{\circ}\text{C} \end{array}$$

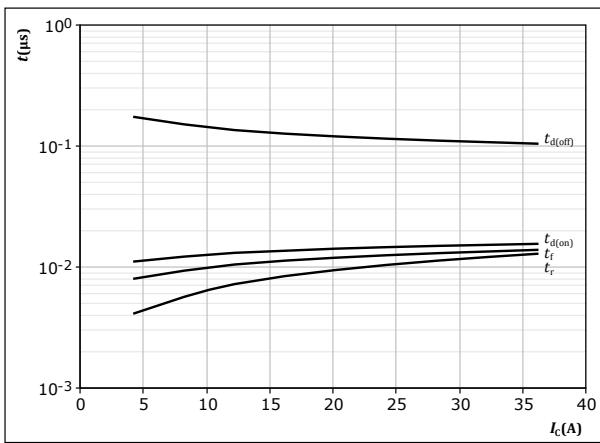


Vincotech

PFC Switching Characteristics

figure 39.

Typical switching times as a function of collector current
 $t = f(I_C)$



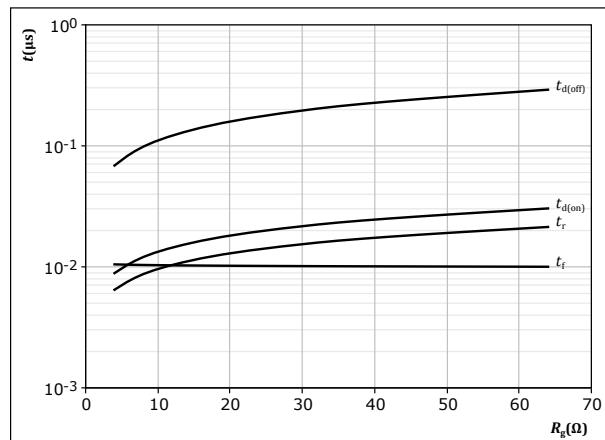
With an inductive load at

$T_j =$	150	°C
$V_{CE} =$	400	V
$V_{GE} =$	0/15	V
$R_{gon} =$	16	Ω
$R_{goff} =$	16	Ω

IGBT

figure 40.

Typical switching times as a function of gate resistor
 $t = f(R_g)$



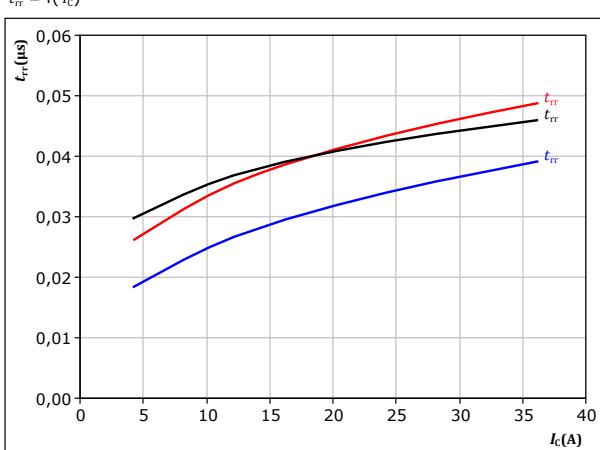
With an inductive load at

$T_j =$	150	°C
$V_{CE} =$	400	V
$V_{GE} =$	0/15	V
$I_C =$	20	A

IGBT

figure 41.

Typical reverse recovery time as a function of collector current
 $t_{rr} = f(I_C)$



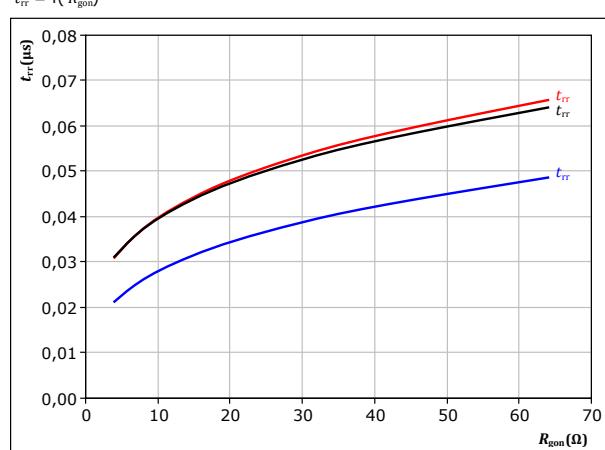
With an inductive load at

$V_{CE} =$	400	V
$V_{GE} =$	0/15	V
$R_{gon} =$	16	Ω

FWD

figure 42.

Typical reverse recovery time as a function of IGBT turn on gate resistor
 $t_{rr} = f(R_{gon})$



With an inductive load at

$V_{CE} =$	400	V
$V_{GE} =$	0/15	V
$I_C =$	20	A

FWD



Vincotech

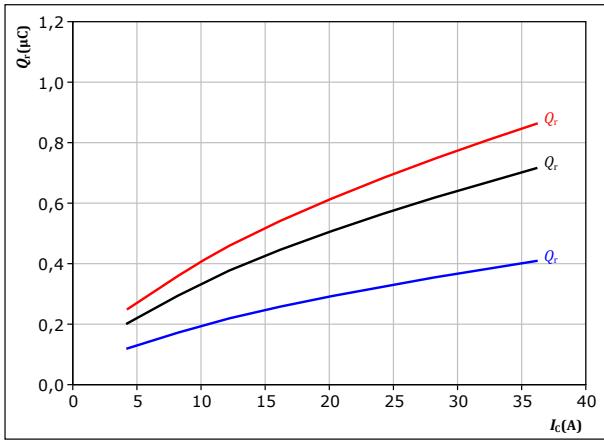
PFC Switching Characteristics

figure 43.

FWD

Typical recovered charge as a function of collector current

$$Q_r = f(I_c)$$



With an inductive load at

$$\begin{aligned} V_{CE} &= 400 \text{ V} \\ V_{GE} &= 0/15 \text{ V} \\ R_{gon} &= 16 \Omega \end{aligned}$$

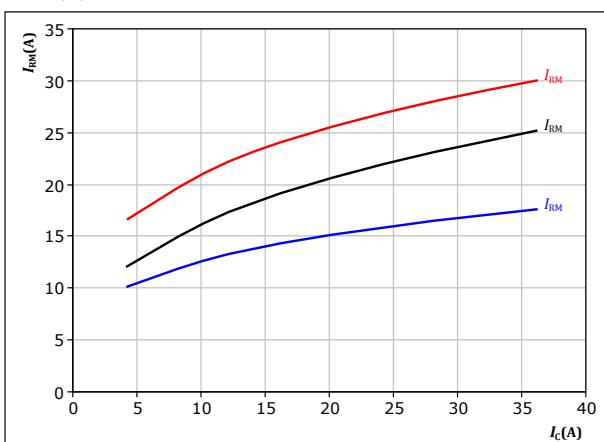
$$\begin{aligned} T_f &= 125 \text{ °C} \\ I_c &= 20 \text{ A} \end{aligned}$$

figure 45.

FWD

Typical peak reverse recovery current as a function of collector current

$$I_{RM} = f(I_c)$$



With an inductive load at

$$\begin{aligned} V_{CE} &= 400 \text{ V} \\ V_{GE} &= 0/15 \text{ V} \\ R_{gon} &= 16 \Omega \end{aligned}$$

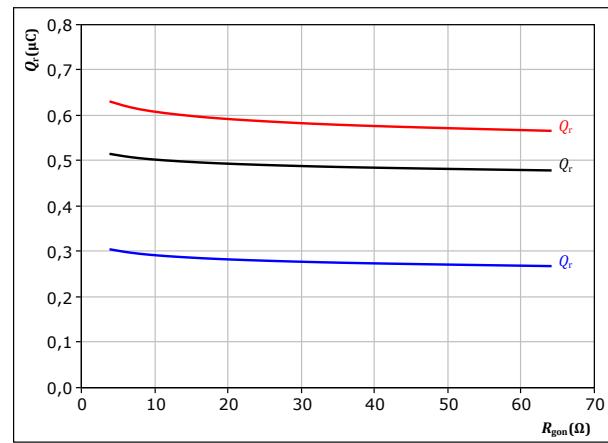
$$\begin{aligned} T_f &= 125 \text{ °C} \\ I_c &= 20 \text{ A} \end{aligned}$$

figure 44.

FWD

Typical recovered charge as a function of turn on gate resistor

$$Q_r = f(R_{gon})$$



With an inductive load at

$$\begin{aligned} V_{CE} &= 400 \text{ V} \\ V_{GE} &= 0/15 \text{ V} \\ I_c &= 20 \text{ A} \end{aligned}$$

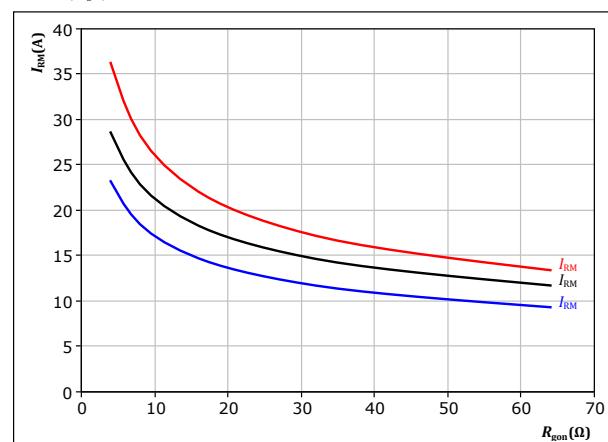
$$\begin{aligned} T_f &= 125 \text{ °C} \\ R_{gon} &= 16 \Omega \end{aligned}$$

figure 46.

FWD

Typical peak reverse recovery current as a function of turn on gate resistor

$$I_{RM} = f(R_{gon})$$



With an inductive load at

$$\begin{aligned} V_{CE} &= 400 \text{ V} \\ V_{GE} &= 0/15 \text{ V} \\ I_c &= 20 \text{ A} \end{aligned}$$

$$\begin{aligned} T_f &= 125 \text{ °C} \\ R_{gon} &= 16 \Omega \end{aligned}$$

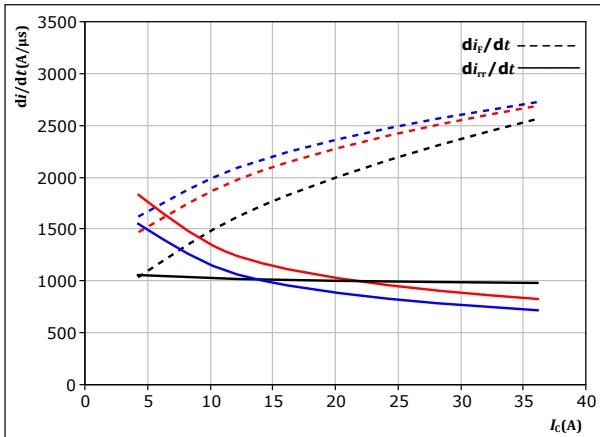


Vincotech

PFC Switching Characteristics

figure 47. FWD

Typical rate of fall of forward and reverse recovery current as a function of collector current
 $di_f/dt, di_{rr}/dt = f(I_c)$

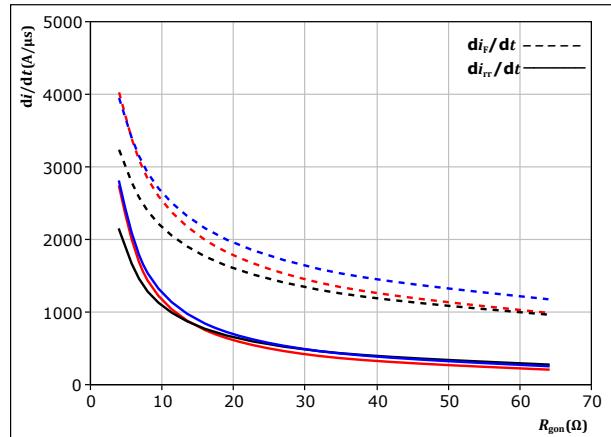


With an inductive load at

$V_{CE} = 400$ V $T_j = 25$ °C
 $V_{GE} = 0/15$ V $T_j = 125$ °C
 $R_{gon} = 16$ Ω $T_j = 150$ °C

figure 48. FWD

Typical rate of fall of forward and reverse recovery current as a function of turn on gate resistor
 $di_f/dt, di_{rr}/dt = f(R_{gon})$



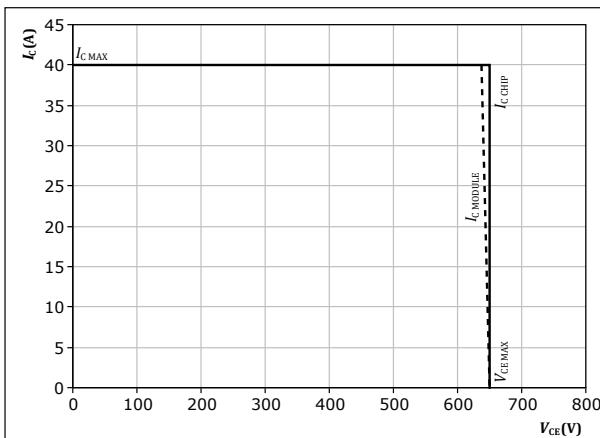
With an inductive load at

$V_{CE} = 400$ V $T_j = 25$ °C
 $V_{GE} = 0/15$ V $T_j = 125$ °C
 $I_c = 20$ A $T_j = 150$ °C

figure 49. IGBT

Reverse bias safe operating area

$I_c = f(V_{CE})$



At $T_j = 150$ °C
 $R_{gon} = 16$ Ω
 $R_{goff} = 16$ Ω



Vincotech

Switching Definitions

figure 50. IGBT

Turn-off Switching Waveforms & definition of t_{doff} , t_{Eoff} (t_{Eoff} = integrating time for E_{off})

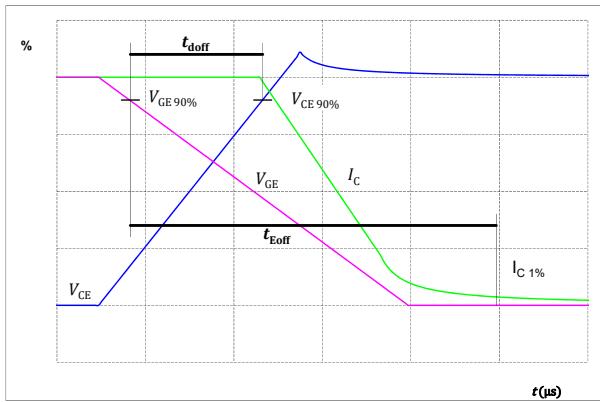


figure 52. IGBT

Turn-off Switching Waveforms & definition of t_f

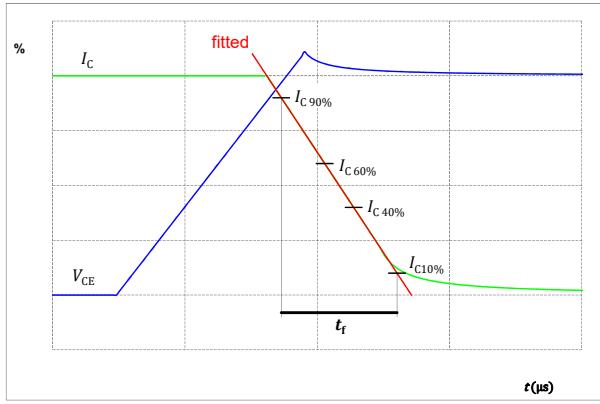


figure 51. IGBT

Turn-on Switching Waveforms & definition of t_{don} , t_{Eon} (t_{Eon} = integrating time for E_{on})

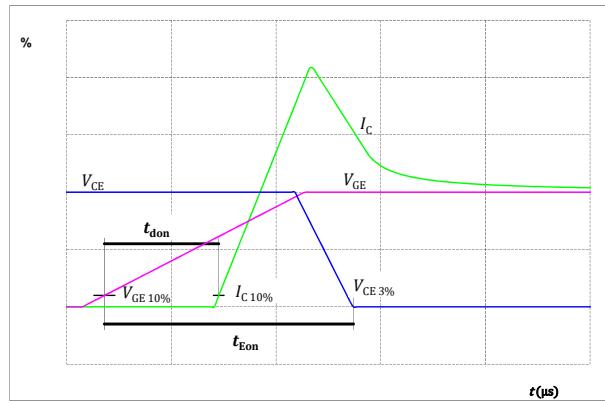
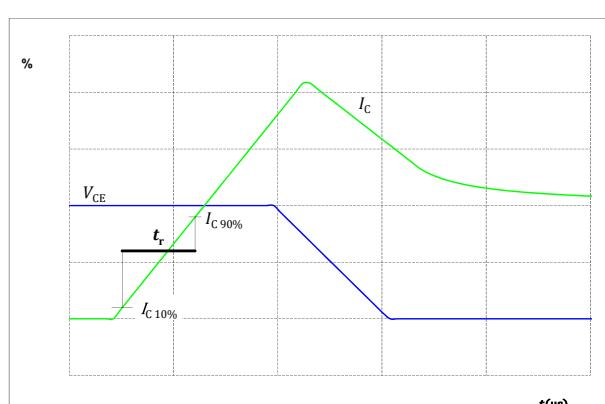


figure 53. IGBT

Turn-on Switching Waveforms & definition of t_r





Vincotech

Switching Definitions

figure 54.

Turn-off Switching Waveforms & definition of t_{tr}

FWD

Turn-off Switching Waveforms & definition of t_{tr}

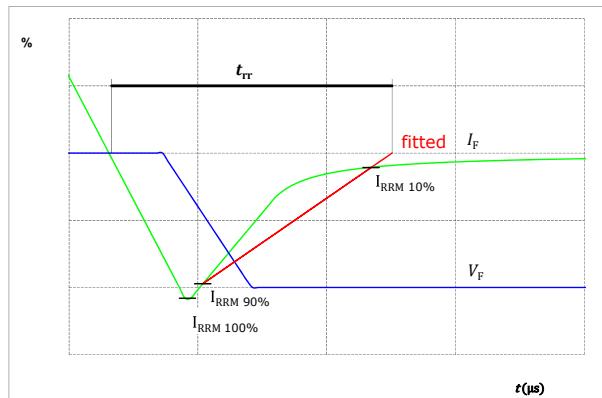
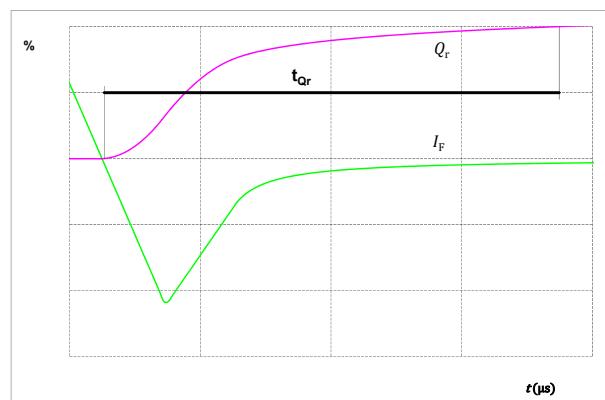


figure 55.

Turn-on Switching Waveforms & definition of t_{qr} (t_{qr} = integrating time for Q_r)

FWD

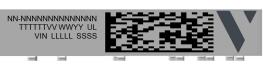
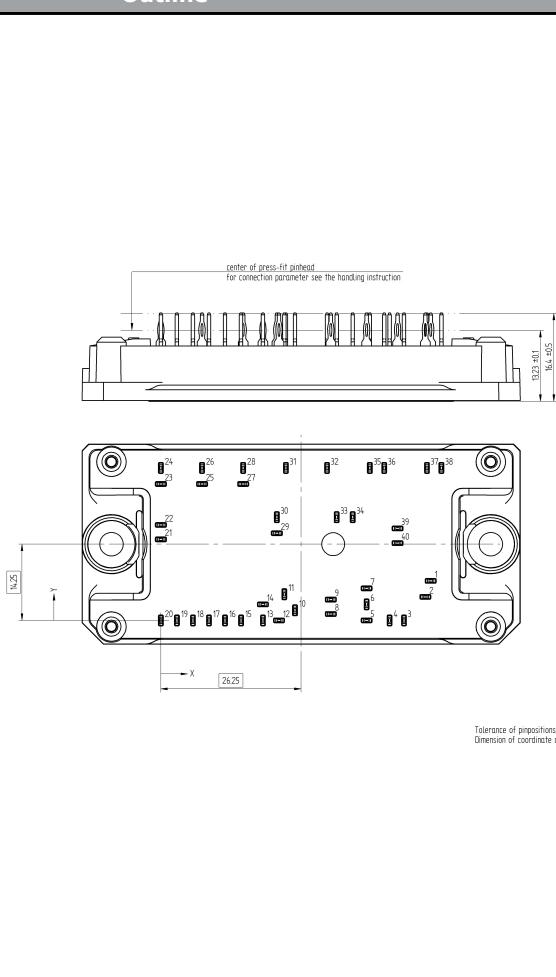
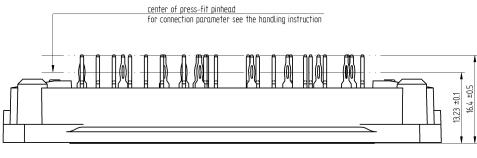
Turn-on Switching Waveforms & definition of t_{qr} (t_{qr} = integrating time for Q_r)



**10-PG06PPA020SJ-LJ01B08T**

datasheet

Vincotech

Ordering Code																																																																																																																																																																										
Version			Ordering Code																																																																																																																																																																							
Without thermal paste			10-PG06PPA020SJ-LJ01B08T																																																																																																																																																																							
With thermal paste			10-PG06PPA020SJ-LJ01B08T-/3/																																																																																																																																																																							
Marking																																																																																																																																																																										
 	Text	Name NN-NNNNNNNNNNNNNN TTTTTTVV	Date code WWYY	UL & VIN UL VIN	Lot LLLL																																																																																																																																																																					
	Datamatrix	Type&Ver TTTTTTVV	Lot number LLLLL	Serial SSSS	Date code WWYY																																																																																																																																																																					
Outline																																																																																																																																																																										
Pin table [mm]	 <table border="1"><thead><tr><th>Pin</th><th>X</th><th>Y</th><th>Function</th></tr></thead><tbody><tr><td>1</td><td>50,5</td><td>7,4</td><td>S2sh1</td></tr><tr><td>2</td><td>49,5</td><td>4,4</td><td>S1sh1</td></tr><tr><td>3</td><td>45,5</td><td>0</td><td>DC-Rect</td></tr><tr><td>4</td><td>42,8</td><td>0</td><td>DC-Rect</td></tr><tr><td>5</td><td>38,5</td><td>0</td><td>PFC-</td></tr><tr><td>6</td><td>38,5</td><td>3</td><td>S1sh2</td></tr><tr><td>7</td><td>38,5</td><td>6</td><td>S2sh2</td></tr><tr><td>8</td><td>31,8</td><td>1,2</td><td>PFC+</td></tr><tr><td>9</td><td>31,8</td><td>3,9</td><td>PFC+</td></tr><tr><td>10</td><td>25,1</td><td>1,9</td><td>S1sh3</td></tr><tr><td>11</td><td>23,1</td><td>4,9</td><td>S2sh3</td></tr><tr><td>12</td><td>22,1</td><td>0</td><td>PFC-</td></tr><tr><td>13</td><td>19,1</td><td>0</td><td>Therm1</td></tr><tr><td>14</td><td>19,1</td><td>3</td><td>Therm2</td></tr><tr><td>15</td><td>15</td><td>0</td><td>G11</td></tr><tr><td>16</td><td>12</td><td>0</td><td>DC-1</td></tr><tr><td>17</td><td>9</td><td>0</td><td>G13</td></tr><tr><td>18</td><td>6</td><td>0</td><td>DC-2</td></tr><tr><td>19</td><td>3</td><td>0</td><td>G15</td></tr><tr><td>20</td><td>0</td><td>0</td><td>DC-3</td></tr><tr><td>21</td><td>0</td><td>15,15</td><td>DC+Inv</td></tr><tr><td>22</td><td>0</td><td>17,85</td><td>DC+Inv</td></tr><tr><td>23</td><td>0</td><td>25,5</td><td>G16</td></tr><tr><td>24</td><td>0</td><td>28,5</td><td>Ph3</td></tr><tr><td>25</td><td>7,7</td><td>25,5</td><td>G14</td></tr><tr><td>26</td><td>7,7</td><td>28,5</td><td>Ph2</td></tr><tr><td>27</td><td>15,4</td><td>25,5</td><td>G12</td></tr><tr><td>28</td><td>15,4</td><td>28,5</td><td>Ph1</td></tr><tr><td>29</td><td>21,7</td><td>16,3</td><td>G27</td></tr><tr><td>30</td><td>21,7</td><td>19,3</td><td>S27</td></tr><tr><td>31</td><td>23,4</td><td>28,5</td><td>PFC2</td></tr><tr><td>32</td><td>31,1</td><td>28,5</td><td>PFC1</td></tr><tr><td>33</td><td>32,9</td><td>19,3</td><td>G25</td></tr><tr><td>34</td><td>35,9</td><td>19,3</td><td>S25</td></tr><tr><td>35</td><td>39,1</td><td>28,5</td><td>DC+Rect</td></tr><tr><td>36</td><td>41,8</td><td>28,5</td><td>DC+Rect</td></tr><tr><td>37</td><td>49,8</td><td>28,5</td><td>ACIn1</td></tr><tr><td>38</td><td>52,5</td><td>28,5</td><td>ACIn1</td></tr><tr><td>39</td><td>44,3</td><td>17,2</td><td>ACIn2</td></tr><tr><td>40</td><td>44,3</td><td>14,45</td><td>ACIn2</td></tr></tbody></table>	Pin	X	Y	Function	1	50,5	7,4	S2sh1	2	49,5	4,4	S1sh1	3	45,5	0	DC-Rect	4	42,8	0	DC-Rect	5	38,5	0	PFC-	6	38,5	3	S1sh2	7	38,5	6	S2sh2	8	31,8	1,2	PFC+	9	31,8	3,9	PFC+	10	25,1	1,9	S1sh3	11	23,1	4,9	S2sh3	12	22,1	0	PFC-	13	19,1	0	Therm1	14	19,1	3	Therm2	15	15	0	G11	16	12	0	DC-1	17	9	0	G13	18	6	0	DC-2	19	3	0	G15	20	0	0	DC-3	21	0	15,15	DC+Inv	22	0	17,85	DC+Inv	23	0	25,5	G16	24	0	28,5	Ph3	25	7,7	25,5	G14	26	7,7	28,5	Ph2	27	15,4	25,5	G12	28	15,4	28,5	Ph1	29	21,7	16,3	G27	30	21,7	19,3	S27	31	23,4	28,5	PFC2	32	31,1	28,5	PFC1	33	32,9	19,3	G25	34	35,9	19,3	S25	35	39,1	28,5	DC+Rect	36	41,8	28,5	DC+Rect	37	49,8	28,5	ACIn1	38	52,5	28,5	ACIn1	39	44,3	17,2	ACIn2	40	44,3	14,45	ACIn2	 <p>center of press-fit pinhead For connection parameter see the handling instruction</p>				
Pin	X	Y	Function																																																																																																																																																																							
1	50,5	7,4	S2sh1																																																																																																																																																																							
2	49,5	4,4	S1sh1																																																																																																																																																																							
3	45,5	0	DC-Rect																																																																																																																																																																							
4	42,8	0	DC-Rect																																																																																																																																																																							
5	38,5	0	PFC-																																																																																																																																																																							
6	38,5	3	S1sh2																																																																																																																																																																							
7	38,5	6	S2sh2																																																																																																																																																																							
8	31,8	1,2	PFC+																																																																																																																																																																							
9	31,8	3,9	PFC+																																																																																																																																																																							
10	25,1	1,9	S1sh3																																																																																																																																																																							
11	23,1	4,9	S2sh3																																																																																																																																																																							
12	22,1	0	PFC-																																																																																																																																																																							
13	19,1	0	Therm1																																																																																																																																																																							
14	19,1	3	Therm2																																																																																																																																																																							
15	15	0	G11																																																																																																																																																																							
16	12	0	DC-1																																																																																																																																																																							
17	9	0	G13																																																																																																																																																																							
18	6	0	DC-2																																																																																																																																																																							
19	3	0	G15																																																																																																																																																																							
20	0	0	DC-3																																																																																																																																																																							
21	0	15,15	DC+Inv																																																																																																																																																																							
22	0	17,85	DC+Inv																																																																																																																																																																							
23	0	25,5	G16																																																																																																																																																																							
24	0	28,5	Ph3																																																																																																																																																																							
25	7,7	25,5	G14																																																																																																																																																																							
26	7,7	28,5	Ph2																																																																																																																																																																							
27	15,4	25,5	G12																																																																																																																																																																							
28	15,4	28,5	Ph1																																																																																																																																																																							
29	21,7	16,3	G27																																																																																																																																																																							
30	21,7	19,3	S27																																																																																																																																																																							
31	23,4	28,5	PFC2																																																																																																																																																																							
32	31,1	28,5	PFC1																																																																																																																																																																							
33	32,9	19,3	G25																																																																																																																																																																							
34	35,9	19,3	S25																																																																																																																																																																							
35	39,1	28,5	DC+Rect																																																																																																																																																																							
36	41,8	28,5	DC+Rect																																																																																																																																																																							
37	49,8	28,5	ACIn1																																																																																																																																																																							
38	52,5	28,5	ACIn1																																																																																																																																																																							
39	44,3	17,2	ACIn2																																																																																																																																																																							
40	44,3	14,45	ACIn2																																																																																																																																																																							

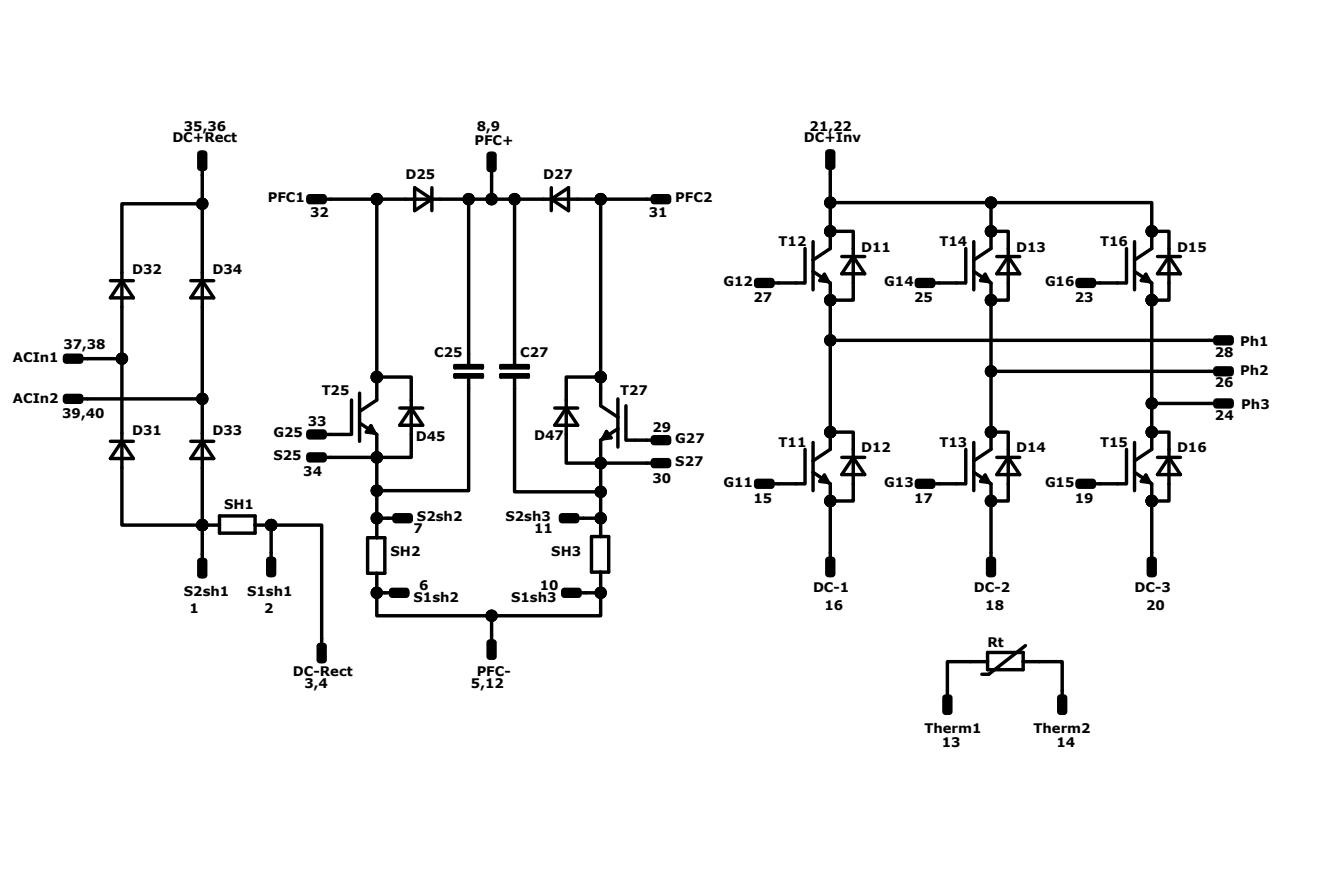


10-PG06PPA020SJ-LJ01B08T

datasheet

Vincotech

Pinout



Identification

ID	Component	Voltage	Current	Function	Comment
T11, T12, T13, T14, T15, T16	IGBT	600 V	20 A	Inverter Switch	
D11, D12, D13, D14, D15, D16	FWD	600 V	15 A	Inverter Diode	
T25, T27	IGBT	650 V	20 A	PFC Switch	
D25, D27	FWD	650 V	20 A	PFC Diode	
D45, D47	FWD	650 V	6 A	PFC Sw. Protection Diode	
D31, D32, D33, D34	Rectifier	1600 V	31 A	Rectifier Diode	
SH1	Resistor			PFC Shunt	
SH2, SH3	Resistor			Shunt	
C25, C27	Capacitor	630 V		Capacitor (PFC)	
Rt	Thermistor			Thermistor	

**10-PG06PPA020SJ-LJ01B08T**

datasheet

Vincotech**Packaging instruction**

Standard packaging quantity (SPQ) 100	>SPQ	Standard	<SPQ	Sample
---------------------------------------	------	----------	------	--------

Handling instruction

Handling instructions for flow 1 packages see vincotech.com website.

Package data

Package data for flow 1 packages see vincotech.com website.

Vincotech thermistor reference

See Vincotech thermistor reference table at vincotech.com website.

UL recognition and file number

This device is certified according to UL 1557 standard, UL file number E192116. For more information see vincotech.com website.



Document No.:	Date:	Modification:	Pages
10-PG06PPA020SJ-LJ01B08T-D1-14	14 Sep. 2020		

DISCLAIMER

The information, specifications, procedures, methods and recommendations herein (together "information") are presented by Vincotech to reader in good faith, are believed to be accurate and reliable, but may well be incomplete and/or not applicable to all conditions or situations that may exist or occur. Vincotech reserves the right to make any changes without further notice to any products to improve reliability, function or design. No representation, guarantee or warranty is made to reader as to the accuracy, reliability or completeness of said information or that the application or use of any of the same will avoid hazards, accidents, losses, damages or injury of any kind to persons or property or that the same will not infringe third parties rights or give desired results. It is reader's sole responsibility to test and determine the suitability of the information and the product for reader's intended use.

LIFE SUPPORT POLICY

Vincotech products are not authorised for use as critical components in life support devices or systems without the express written approval of Vincotech.

As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in labelling can be reasonably expected to result in significant injury to the user.
2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.